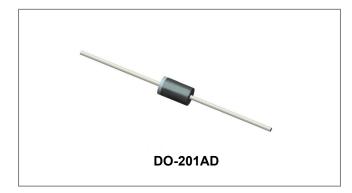


31DQ09 31DQ10

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# 31DQ09/31DQ10 SCHOTTKY RECTIFIER



#### **Features**

- Low profile, axial leaded outline
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Very Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Terminals finish: Tin Lead-free plated
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

#### Applications

- Switching power supply
- Converters
- **Free-Wheeling diodes**
- **Reverse battery protection**

### Maximum Ratings(limiting values, Tc =25°C unless otherwise specified)

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	-	90(31DQ90) 100(31DQ10)	V
Average Forward Current	IF(AV)	50% duty cycle @T <sub>c</sub> =53.4°C, rectangular wave form	3.3	А
Peak One Cycle Non-Repetitive Surge Current	I <sub>FSM</sub>	8.3 ms, half Sine pulse	42	А

#### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	V <sub>F1</sub>	@ 3A, Pulse, T <sub>J</sub> = 25 °C	0.77	0.85	V
		@ 6 A, Pulse, T」 = 25 °C	-	0.97	v
	V <sub>F2</sub>	@ 3 A, Pulse, T」 = 125 °C	0.63	0.69	V
		@ 6 A, Pulse, TJ = 125 °C	-	0.80	v
Reverse Current*	I <sub>R1</sub>	$@V_R = Rated V_R$ , Pulse, T <sub>J</sub> = 25 °C	0.0001	1	mA
	I <sub>R2</sub>	$@V_R = Rated V_R, Pulse, T_J = 125 °C$	0.04	3	mA
Junction Capacitance	Ст	@V <sub>R</sub> = 5V, T <sub>C</sub> = 25 °C f <sub>SIG</sub> = 1MHz	92	110	PF
Typical Series Inductance	Ls	Measured lead to lead 5 mm from 9.0 -		-	nH
Voltage Rate of Change	dv/dt	-	-	10,000	V/µs

ruise width 300 µs, a

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### **Circuit Diagram**



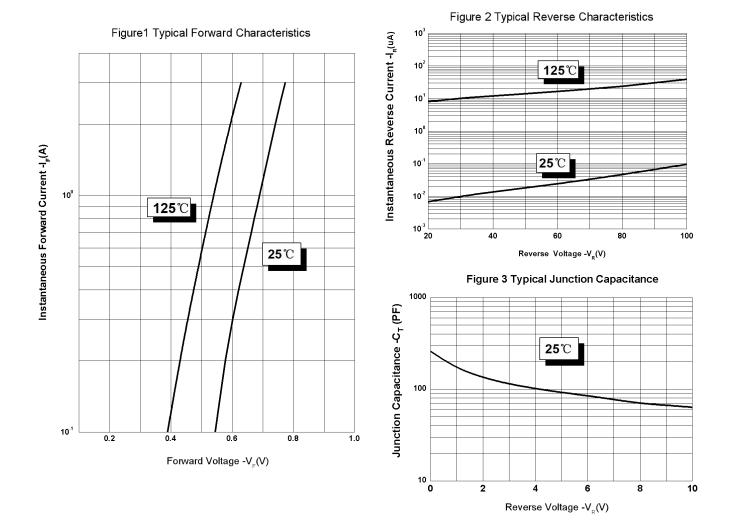


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# **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-40 to +150	°C
Storage Temperature	T <sub>stg</sub>	-	-40 to +150	°C
Typical Thermal Resistance Junction to Ambient	R <sub>0JA</sub>	-	80	°C/W
Typical Thermal Resistance Junction to Lead	R <sub>θJL</sub>	-	34	°C/W
Approximate Weight	wt	-	1.02	g

# **Ratings and Characteristics Curves**



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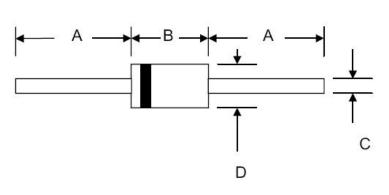


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# **Mechanical Dimensions DO-201AD**



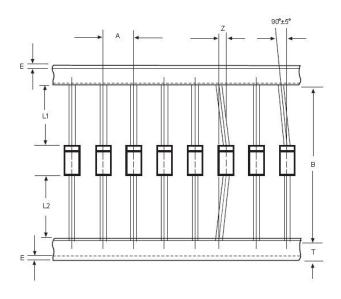
SYMBOL	Millimeters		Inches		
SYMBOL	Min.	Max.	Min.	Max.	
А	25.4	-	1.000	-	
В	8.50	9.50	0.335	0.374	
С	1.2	1.3	0.048	0.052	
D	5.0	5.6	0.197	0.220	

# **Ordering Information**

Device	Device Package		
31DQ09(10)	DO-201AD	1250pcs /Tape	
510009(10)	(Pb-Free)		
31DQ09(10)TA	DO-201AD	1250pcs /Tape	
	(Pb-Free)	1250pcs/Tape	

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

### **Carrier Tape Specification DO-201AD**



Ş	
000 XXX	69
310	- <u>25</u> -26
	31DQ09 SSG XXXXX

Marking Diagram

Where XXXXX is YYWWL

- 31DQ09 = Part Name
- SSG = SSG
  - = Year

YY

ww

L

- = Week
- = Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0

SYMBOL	Millimeters		
STMBOL	Min.	Max.	
А	9.50	10.50	
В	50.9	53.9	
Z	-	1.20	
Т	5.60	6.40	
E	-	0.80	
IL1-L2I	_	1.0	



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